

## 16-Bit 500 kHz Wide Temperature Range Sampling ADC

AD1385

PRODUCT FEATURES
16-Bit Resolution
500 kHz Sampling Rate
Differential Linearity Autocalibration
Specified over −55°C to +125°C Range
SNR 90 dB @ 100 kHz (min)
THD −88 dB @ 100 kHz (min)
0.0006% FSR DNL (typ)
0.0015% FSR INL (typ)
±5, ±10 V Bipolar Input Ranges
Zero Offset Autocalibration

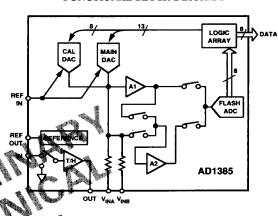
APPLICATIONS
Medical Imaging
CAT
Magnetic Resonance
Radar
Vibration Analysis
Parametric Measurement Unit (ATE)
Digital Storage Oscilloscopes
Waveform Recorders
Analytical Instruments

#### PRODUCT DESCRIPTION

The AD1385 is a complete 500 kHz, 16-bit, samplify malogited digital converter contained in a single package. Its differential linearity autocalibration feature allows this high resolution, high speed converter to offer outstanding noise and distortion performance, as well as excellent INL and DNL specifications, over the full military temperature range. Autocalibration effectively eliminates DNL drift over temperature.

The AD1385 architecture includes a low noise, low distortion track/hold, a three pass digitally corrected subranging ADC, and linearity calibration circuitry. A complete linearity calibration requires only 15 ms. Precision thin-film resistors and a proprietary DAC contribute to the part's outstanding dynamic and static performance.

## FUNCTIONAL BLOCK DIAGRAM



 $\pm$ 0 AD1385 uses four power supplies,  $\pm$ 5 V and  $\pm$ 15 V, and an external 10 MHz clock. Power dissipation is nominally 2.76 W. Two user selectable bipolar input ranges,  $\pm$ 5 V and  $\pm$ 10 V, are provided. Careful attention to grounding and a single package make it easy to design PCBs to achieve specified performance.

The AD1385's pinout is nearly identical to that of the AD1382. Just two additional connections, to enable and monitor autocalibration, are required. This commonality provides an easy upgrade path to extend system performance and operating temperature range.

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# **AD1385** — SPECIFICATIONS ( $T_A = +25^{\circ}C$ , $V_S = \pm 15$ V, $V_{DD} = +5$ V, $V_{SS} = -5$ V, 10 MHz External Clock, unless otherwise noted)

Development	Min	AD1385KD Typ	Max	Min	AD1385TD Typ	Max	Units
Parameter	16	Тур	IVEAL	16		TVLGA.	Bits
RESOLUTION	10			10			Dits
ANALOG INPUT		±5, ±10			±5, ±10		l v
Input Ranges Input Impedance	2.45	2.5	2.55	2.45	2.5	2.55	kΩ
TRANSFER CHARACTERISTICS	2.43	2.3	2.33				
(Combined ADC/Track/Hold)							
Integral Nonlinearity <sup>1, 2</sup> , T <sub>MIN</sub> to T <sub>MAX</sub>		±0.0015			±0.0015		% FSR3
Differential Nonlinearity <sup>1</sup>		$\pm 0.0006$	±0.0015		±0.0006	±0.0015	% FSR
		0.3			0.3		ppm/°C
Drift, $T_{MIN}$ to $T_{MAX}$ Missing Codes, $T_{MIN}$ to $T_{MAX}$			None			None	
Gain Error⁴		±0.05	±0.15		±0.05	±0.15	% FSR
Drift, T <sub>MIN</sub> to T <sub>MAX</sub>		8 ±0.05	15 ±0.10		8 ±0.05	15 ±0.10	ppm/°C % FSR
Bipolar Zero <sup>4</sup>		±0.05	±0.10		±0.05	±0.10	ppm/°C
Drift, T <sub>MIN</sub> to T <sub>MAX</sub> PSRR		±0.006	±0.10		±0.006	±0.10	% FSR/
Noise		70	_0.10		70	-0.110	μV RM
DYNAMIC CHARACTERISTICS <sup>2</sup>	<del>                                     </del>						† · · · · · · · ·
$\pm 5 \text{ V FSR}, \text{ V}_{\text{IN}} = -0.4 \text{ dB}, \text{ T}_{\text{MIN}} \text{ to T}_{\text{MAX}}$					ed		į
Sample Rate			500		E.	500	kHz
Signal-to-Noise Ratio <sup>5</sup>					<b>4</b>		
f = 5  kHz	90	93		100	93		dB
f = 100  kHz	90	92	4 F 40	99	92		dB
f = 200  kHz	88	91	F # 49 1	88	91		dB
Peak Distortion	- 00	- th- 13	# #		107		dB
f = 5 kHz f = 100 kHz	_ 90	I I No A			-95		dB
f = 200 kHz	82	68	- 4 N L	82	-88		dB
Total Harmonic Distortion <sup>6</sup>		The same of		50 P			-
f = 5 kHz	- 90	165	1	-90	-105		dB
f = 100  kHz	-88	- 95	1	88	-95		dB
f = 200 kHz	8			-82	-88		dB
DYNAMIC CHARACTERISTICS <sup>2</sup>		THE REAL PROPERTY.	1				
$\pm 10 \text{ V FSR}, V_{IN} = -0.4 \text{ dB}, T_{MIN} \text{ to } T_{MAX}$	-	W 1		-		500	1-77-
Sample Rate		The state of the s	500			500	kHz
Signal-to-Noise Ratio <sup>5</sup> f = 5  kHz	90	95		90	95		dB
f = 3 kHz f = 100 kHz	90	94		90	94		dB
f = 200  kHz	88	93		88	93		dB
Peak Distortion							
f = 5  kHz	-90	-108		-90	-108		dB
f = 100  kHz	-80	-87		-80	-87		dB
f = 200  kHz	-74	-82		-74	-82		dB
Total Harmonic Distortion <sup>6</sup>	-90	-105		-90	-105		dB
f = 5 kHz f = 100 kHz	-80	-103 -87		-80	-87		dB
f = 200  kHz	-74	-82		-74	-82		dB
DIGITAL INPUTS <sup>7</sup>	<del>                                     </del>			+			<u> </u>
Input Voltage							
V <sub>IL</sub>			0.8			0.8	V
VIH	2.25			2.25			V .
Input Current			±200		_	±200	μA
Input Capacitance		2			2		pF
Start Command	١,,			10			
Setup Time, t <sub>SCS</sub>	10 10			10			ns ns
Hold Time, t <sub>SCH</sub> Autozero	10			1.0			
Setup Time, t <sub>AZS</sub>	10			10			ns
Hold Time, t <sub>AZN</sub>	20			20			ns
Calibrate Pulsewidth	20			20			ns
Clock							
Frequency	2.5		10	2.5		10	MHz
Duty Cycle	40	_	60	40	-	60	%
Aperture Delay8	1	7		1	7		ns

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		AD1385KD			AD1385TD		T
Parameter	Min	Тур	Max	Min	Тур	Max	Units
DIGITAL OUTPUTS <sup>7</sup>							
Output Voltage	ł						ľ
V <sub>OL</sub> @ I <sub>OL</sub> = 3.2 mA		0.2	0.4		0.2	0.4	v
$V_{OH}$ @ $I_{OH} = -3.2$ mA		3.5		2.4	3.5		v
Output Capacitance		10			10		pF
Leakage, Outputs Disabled			±200			±200	μA
Data Valid							
Setup Time, t <sub>DVS</sub>	75	125		75	125		ns
Hold Time, t <sub>DVH</sub>	25	50		25	50		ns
Hold Command Time, tH		1300			1300		ns
Hold Command Delay, tHD		6			6		ns
Data Strobe Pulse Width, t <sub>DS</sub>		200		1	200		ns
Data Strobe Delay, t <sub>DSD</sub>		1650		1	1650		ns
Calibration Status Duration		15		<u> </u>	15		ms
OUTPUT CODING	Comp	lementary O	ffset Binary or	Compleme	ntary Twos C	Complement	
INTERNAL REFERENCE							1
Voltage	9.990		10.010	9.990		10.010	v
Current	2	5	<b>\</b>	20	5		mA
Drift		5 ,	13	1	5	15	ppm/°C
TEMPERATURE RANGE, CASE		, (Pe	ge tra	45			
Specified	0		+70	-55		+125	℃
Storage	-65	11 1 1	±150	65		+150	l °C
POWER REQUIREMENTS	. 1	No.				•	1
Specified Operating Range	A . W	P					
±V <sub>S</sub>	4.25	A Last	15.75	14.25		15.75	l v
+V <sub>DD</sub>	4.75		5.25	4.75		5.25	v
$-\mathbf{v}_{ss}^{DD}$	- 25	4.	-4.85 h	-5.25		-4.75	v
Current Drains		<b>1</b>		1			1
+V <sub>S</sub>		52	<b>9</b> 0		52	80	mA
$-v_s^3$		48	75	1	48	75	mA
+V <sub>DD</sub>	<b>*</b>	10	160		104	160	mA
-V <sub>SS</sub>		148	200		148	200	mA
Power Dissipation		2.76	4.125	1	2.76	4.125	Watts

#### NOTES

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<sup>&</sup>lt;sup>1</sup>Integral linearity is inferred from FFTs. Differential linearity is derived from histograms.

Performance over temperature is specified within ±15°C of the temperature at which the last calibration was performed.

<sup>&</sup>lt;sup>3</sup>FSR = Full-Scale Range.

<sup>&</sup>lt;sup>4</sup>Adjustable to zero.

<sup>&</sup>lt;sup>5</sup>SNR excludes harmonics 2-9 of the fundamental.

THD includes harmonics 2-9 of the fundamental.

<sup>&</sup>lt;sup>7</sup>Refer to Figures 17, 18 and 24. Guaranteed over operating temperature range, not 100% production tested.

<sup>&</sup>lt;sup>8</sup>Aperture delay is the time from the rising edge on the Hold Command Input to the opening of the switch in the Track/Hold.

Specifications subject to change without notice.

## AD1385

## ABSOLUTE MAXIMUM RATINGS\*

+V <sub>S</sub> to AGND
-V <sub>s</sub> to AGND18 V
V <sub>DD</sub> to PGND
V <sub>SS</sub> to PGND
AGND to PGND
Analog Inputs
Reference Input 0 V to +11 V
Digital Inputs $-0.3 \text{ V}$ to $V_{DD} + 0.3 \text{ V}$
Output Short Circuit Duration
Reference Output Indefinite
Track/Hold Output
Digital Outputs 1 sec for Any One Output
Case Temperature (Operating)55°C to +125°C
Storage Temperature65°C to +150°C

<sup>\*</sup>Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ORDERING GUIDE**

Model	Temperature Range (Case)	Package Option		
AD1385KD	0°C to +70°C	DH#8A		
Ad1385TD	-55°C to +125°C	DH-88A		
AD1385TD/883B	-55°C to +125°€	DN 48A		

<sup>\*</sup>DH-48A = Bottom Brazed Ceramic DIP. For outline information see Page Information section.

## **AD1385 PIN CONNECTIONS**

The AD1385 is housed in a 48-pin bottom-brazed ceramic bathtub package. The pinout is as follows:

Pin	Function	Pin	Function
1	CLOCK IN	48	V <sub>DD2</sub> (+5 V POWER)
2	POWER GROUND	47	POWER GROUND
3	B1/B9 (MSB)	46	V <sub>SS2</sub> (-5 V POWER)
4	B2/B10	45	AUTOZERO
5	B3/B11	44	B1 SELECT
6	B4/B12	43	POWER GROUND
7	B5/B13	42	POWER GROUND
8	B6/B14	41	CAL
9	B7/B15	40	GAIN ADJUST
10	B8/B16 (LSB)	39	+10 V REFERENCE OUT
11	V <sub>DD1</sub> (+5 V SIGNAL)	38	$-V_{S1}(-15 \text{ V})$
12	POWER GROUND	37	SIGNAL GROUND
13	V <sub>SS1</sub> (-5 V SIGNAL)	36	$+V_{S1}(+15 \text{ V})$
14	SIGNAL GROUND	35	SIGNAL GROUND
15	DATASTROPE	34	DNC
16	HIT OFFIE SELECT	33	DNC
n I	OE DATA ENABLE	32	+10 V REFERENCE IN
18	START CONVERT	31	V <sub>IN</sub> B
19	HOLD COMMAND OUT	30	V <sub>IN</sub> A
20	SIGNAL CROUND	29	OFFSET ADJUST
21	(+15 V)	28	CAL STATUS
12	HOLD COMMAND IN	27	TRACK/HOLD OUTPUT
23	-V <sub>S2</sub> (-15 V)	26	SIGNAL GROUND
24	POWER GROUND	25	TRACK/HOLD INPUT
- AFF			

DNC = DO NOT CONNECT

## CAUTION

ESD (electrostatic discharge) sensitive device. The digital control inputs are diode protected; however, permanent damage may occur on unconnected devices subject to high energy electrostatic fields. Unused devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are removed.



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